

2SK2466

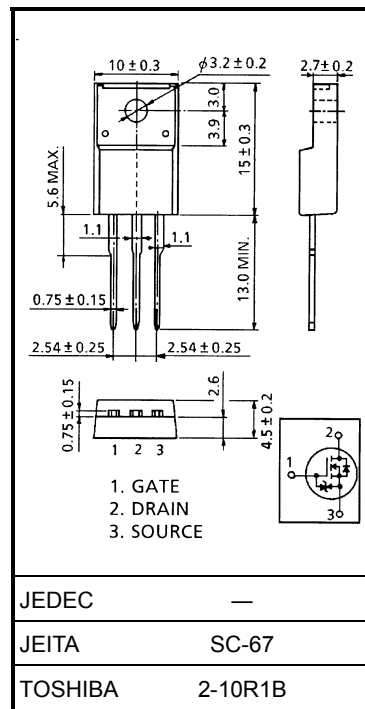
Chopper Regulator, DC-DC Converter and Motor Drive Applications

Unit: mm

- 4-V gate drive
- Low drain-source ON resistance : $R_{DS(ON)} = 34 \text{ m}\Omega$ (typ.)
- High forward transfer admittance : $|Y_{fs}| = 30 \text{ S}$ (typ.)
- Low leakage current : $I_{DSS} = 100 \text{ }\mu\text{A}$ (max) ($V_{DS} = 100 \text{ V}$)
- Enhancement mode : $V_{th} = 0.8 \sim 2.0 \text{ V}$ ($V_{DS} = 10 \text{ V}$, $I_D = 1 \text{ mA}$)

Maximum Ratings ($T_a = 25^\circ\text{C}$)

Characteristics		Symbol	Rating	Unit
Drain-source voltage		V_{DSS}	100	V
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V_{DGR}	100	V
Gate-source voltage		V_{GSS}	± 20	V
Drain current	DC (Note 1)	I_D	30	A
	Pulse (Note 1)	I_{DP}	120	
Drain power dissipation ($T_c = 25^\circ\text{C}$)		P_D	40	W
Single pulse avalanche energy (Note 2)		E_{AS}	293	mJ
Avalanche current		I_{AR}	30	A
Repetitive avalanche energy (Note 3)		E_{AR}	4	mJ
Channel temperature		T_{ch}	150	$^\circ\text{C}$
Storage temperature range		T_{stg}	$-55 \sim 150$	$^\circ\text{C}$



Weight: 1.9 g (typ.)

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	$R_{th(ch-c)}$	3.125	$^\circ\text{C} / \text{W}$
Thermal resistance, channel to ambient	$R_{th(ch-a)}$	62.5	$^\circ\text{C} / \text{W}$

Note 1: Ensure that the channel temperature does not exceed 150°C .

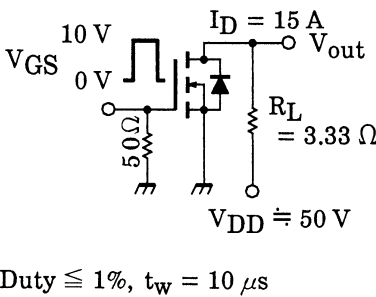
Note 2: $V_{DD} = 25 \text{ V}$, $T_{ch} = 25^\circ\text{C}$ (initial), $L = 525 \text{ }\mu\text{H}$, $R_G = 25 \text{ }\Omega$, $I_{AR} = 30 \text{ A}$

Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.

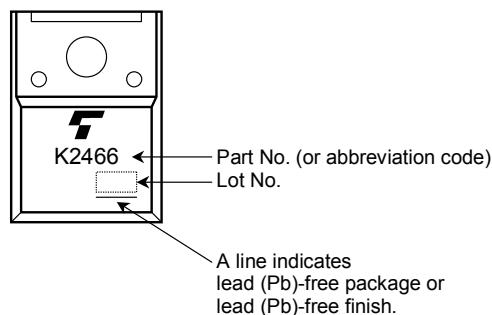
Electrical Characteristics (Ta = 25°C)

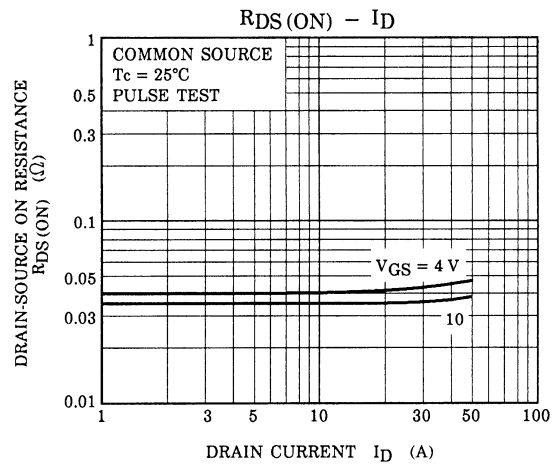
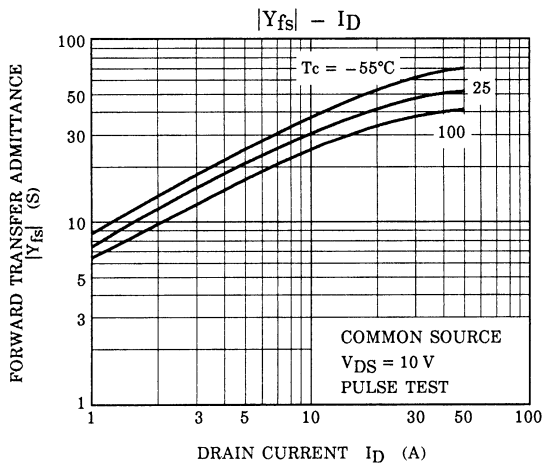
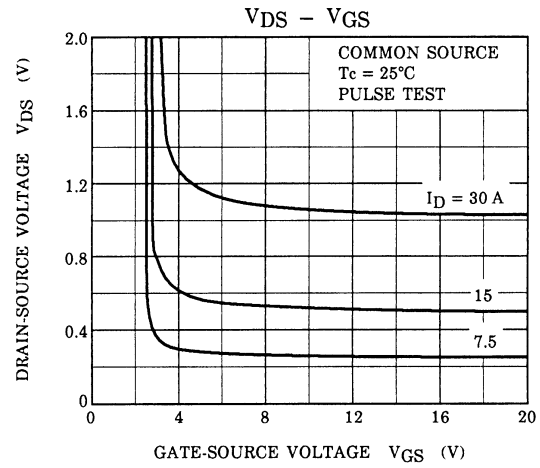
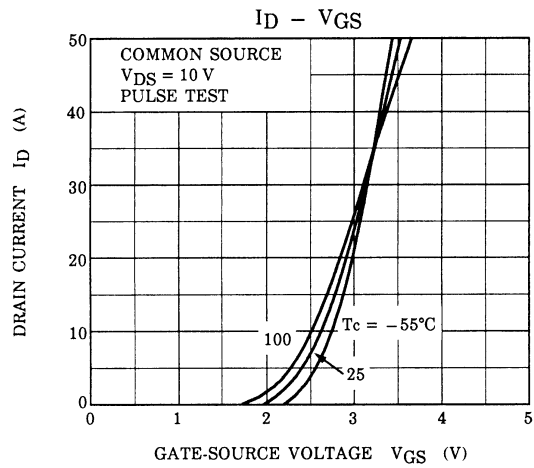
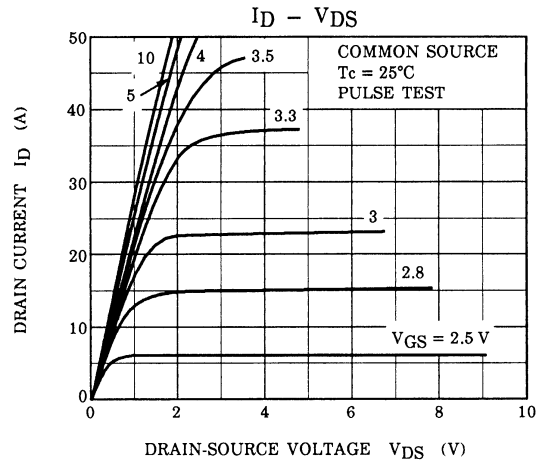
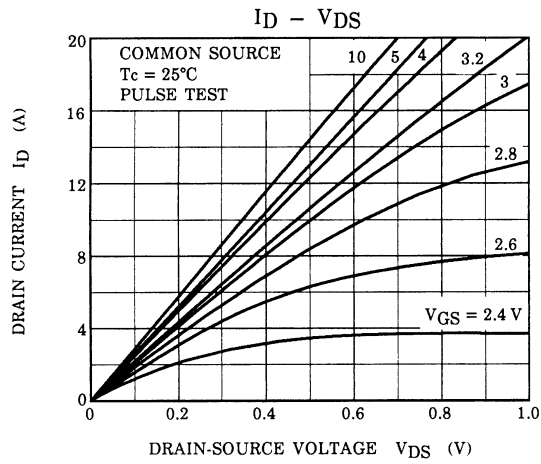
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Gate leakage current	I_{GSS}	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0 \text{ V}$	—	—	± 10	μA
Drain cut-off current	I_{DSS}	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$	—	—	100	μA
Drain-source breakdown voltage	$V_{(BR)DSS}$	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	100	—	—	V
Gate threshold voltage	V_{th}	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$	0.8	—	2.0	V
Drain-source ON resistance	$R_{DS(ON)}$	$V_{GS} = 4 \text{ V}, I_D = 15 \text{ A}$	—	40	70	$\text{m}\Omega$
		$V_{GS} = 10 \text{ V}, I_D = 15 \text{ A}$	—	34	46	
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10 \text{ V}, I_D = 15 \text{ A}$	13	30	—	S
Input capacitance	C_{iss}	$V_{DS} = 10 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ MHz}$	—	3250	—	pF
Reverse transfer capacitance	C_{rss}		—	230	—	
Output capacitance	C_{oss}		—	520	—	
Switching time	Rise time	 V_{GS} 10 V, 0 V $I_D = 15 \text{ A}$ $R_L = 3.33 \Omega$ $V_{DD} \approx 50 \text{ V}$ Duty $\leq 1\%$, $t_w = 10 \mu\text{s}$	—	33	—	ns
	Turn-on time		—	60	—	
	Fall time		—	95	—	
	Turn-off time		—	230	—	
Total gate charge (Gate-source plus gate-drain)	Q_g	$V_{DD} \approx 80 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 30 \text{ A}$	—	68	—	nC
Gate-source charge	Q_{gs}		—	46	—	
Gate-drain ("miller") charge	Q_{gd}		—	22	—	

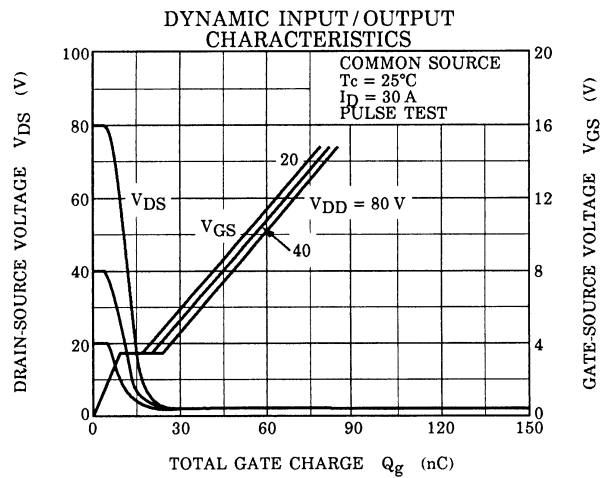
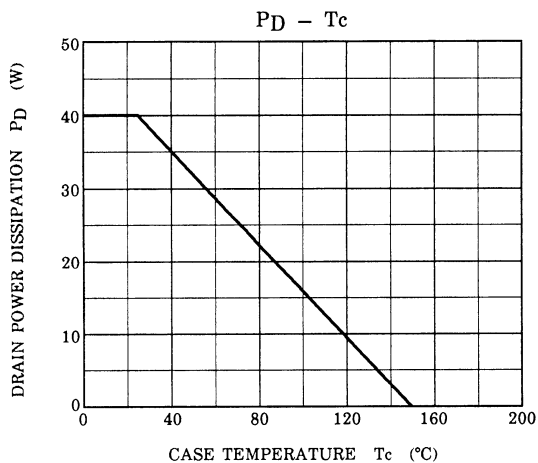
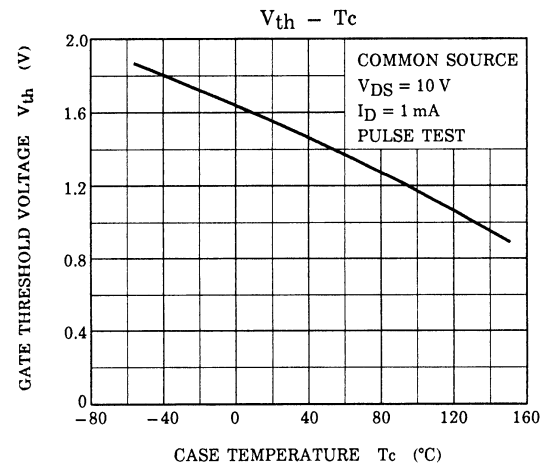
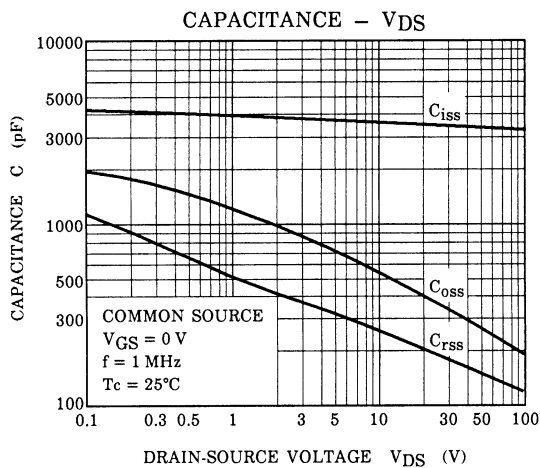
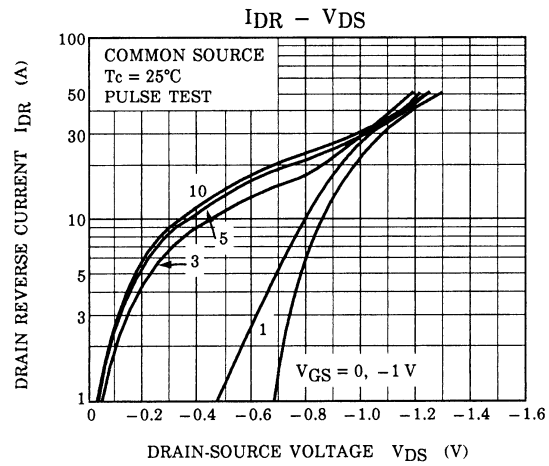
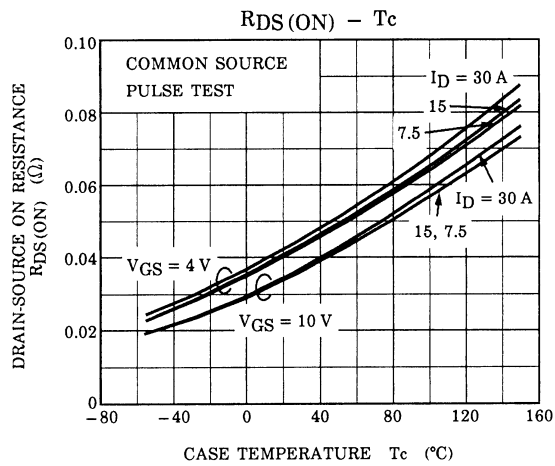
Source-Drain Ratings and Characteristics (Ta = 25°C)

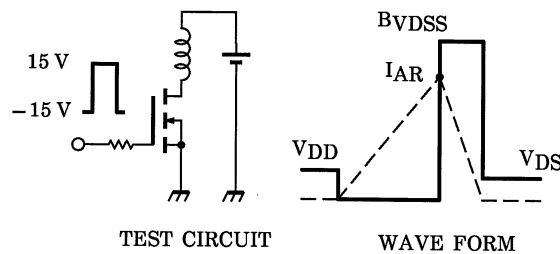
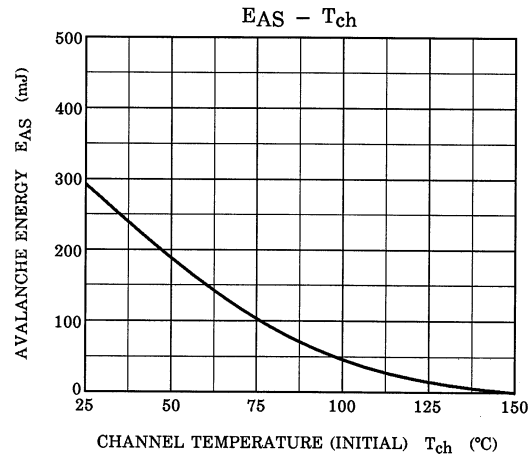
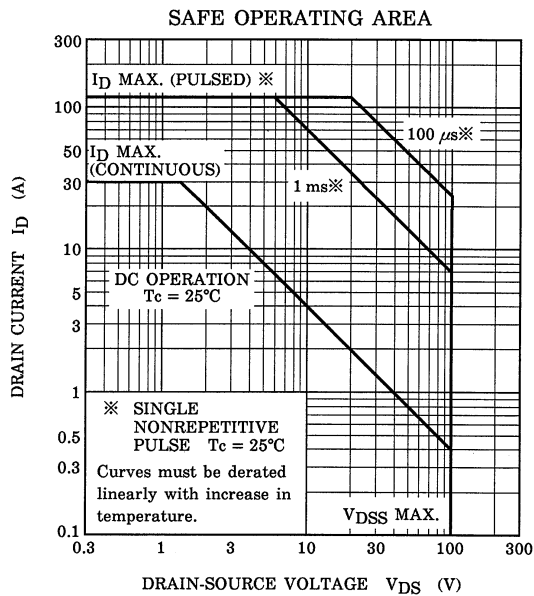
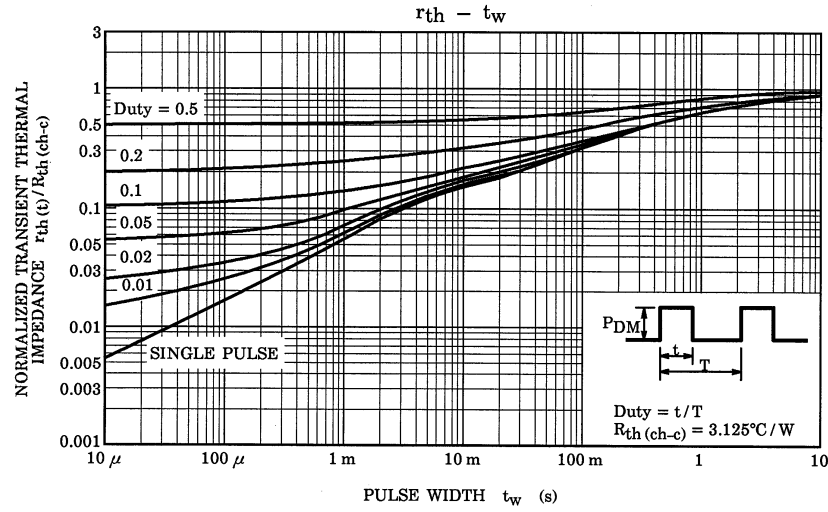
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Continuous drain reverse current (Note 1)	I_{DR}	—	—	—	30	A
Pulse drain reverse current (Note 1)	I_{DRP}	—	—	—	120	A
Forward voltage (diode)	V_{DSF}	$I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V}$	—	—	-1.7	V
Reverse recovery time	t_{rr}	$I_{DR} = 30 \text{ A}, V_{GS} = 0 \text{ V}$	—	120	—	ns
Reverse recovery charge	Q_{rr}	$dI_{DR} / dt = 50 \text{ A} / \mu\text{s}$	—	280	—	μC

Marking









$$R_G = 25 \, \Omega$$

$$V_{DD} = 25 \, \text{V}, L = 525 \, \mu\text{H}$$

$$E_{AS} = \frac{1}{2} \cdot L \cdot I^2 \cdot \left(\frac{B_{VDS}}{B_{VDS} - V_{DD}} \right)$$

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